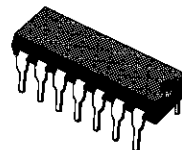
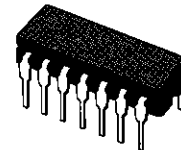


HEX INVERTER (OPEN DRAIN)

- **HIGH SPEED**
 $t_{PD} = 8 \text{ ns}$ (TYP.) AT $V_{CC} = 5 \text{ V}$
- **LOW POWER DISSIPATION**
 $I_{CC} = 1 \mu\text{A}$ (MAX.) AT $T_A = 25^\circ\text{C}$
- **HIGH NOISE IMMUNITY**
 $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (MIN.)
- **OUTPUT DRIVE CAPABILITY**
10 LSTTL LOADS
- **WIDE OPERATING VOLTAGE RANGE**
 $V_{CC} \text{ (OPR)} = 2 \text{ V TO } 6 \text{ V}$
- **PIN AND FUNCTION COMPATIBLE WITH**
54/74LS05



B1R
(Plastic Package)



F1R
(Ceramic Package)



M1R
(Micro Package)



C1R
(Chip Carrier)

ORDER CODES :

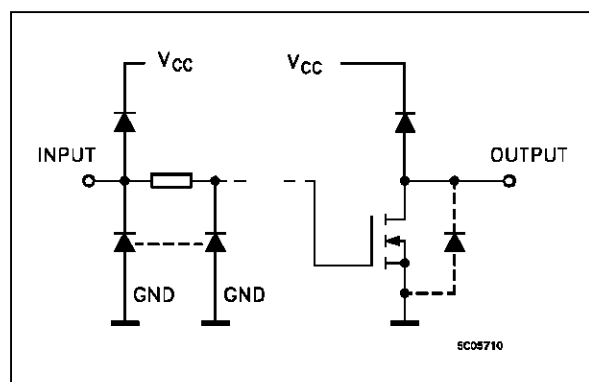
| | |
|------------|------------|
| M54HC05F1R | M74HC05M1R |
| M74HC05B1R | M74HC05C1R |

DESCRIPTION

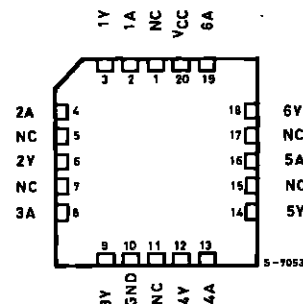
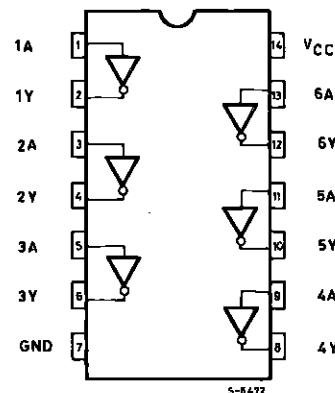
The M54/74HC05 is a high speed CMOS HEX OPEN DRAIN INVERTER fabricated in silicon gate C²MOS technology. It has the same high speed performance of LSTTL combined with true CMOS low power consumption.

The internal circuit is composed of 3 stages including buffer output, which enables high noise immunity and stable output. All inputs are equipped with circuits against static discharge and transient excess voltage.

INPUT AND OUTPUT EQUIVALENT CIRCUIT



PIN CONNECTIONS (top view)



NC =
No Internal
Connection

M54/M74HC05

TRUTH TABLE

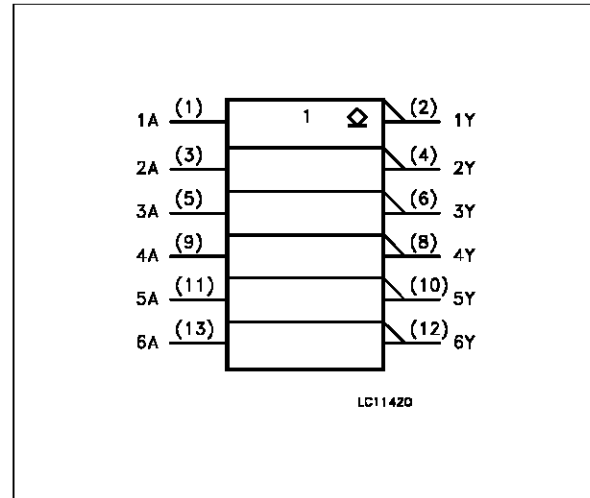
| A | Y |
|---|---|
| L | Z |
| H | L |

Z = High impedance

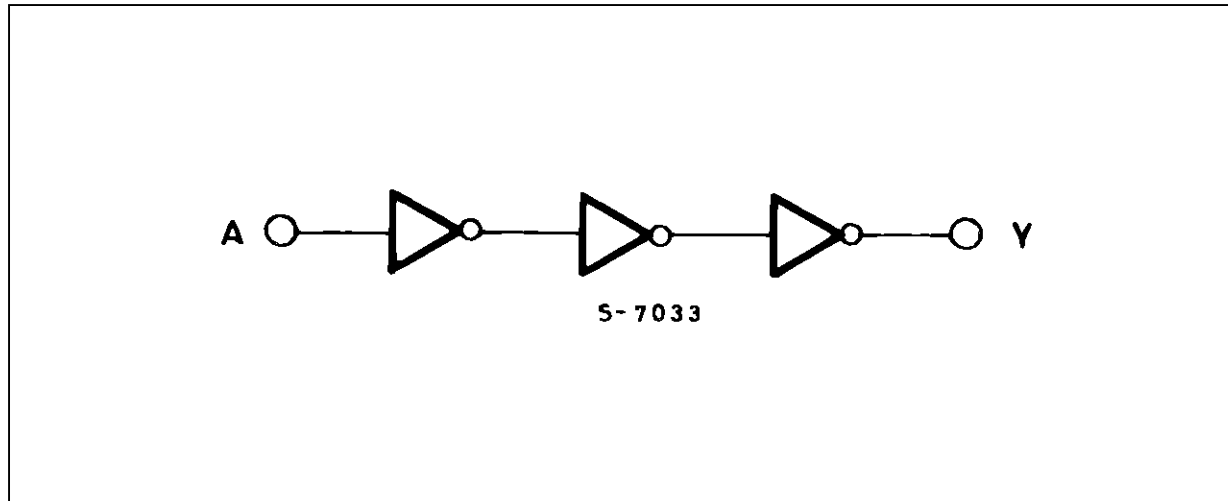
PIN DESCRIPTION

| PIN No | SYMBOL | NAME AND FUNCTION |
|-----------------------|-----------------|-------------------------|
| 1, 3, 5, 9, 11, 13 | 1A to 6A | Data Inputs |
| 2, 4, 6, 8, 10, 12 | 1Y to 6Y | Data Outputs |
| 7 | GND | Ground (0V) |
| 14 | V _{CC} | Positive Supply Voltage |

IEC LOGIC SYMBOL



LOGIC DIAGRAM (Per Gate)



ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
|-------------------------------------|---------------------------------------|-------------------------------|------|
| V _{CC} | Supply Voltage | -0.5 to +7 | V |
| V _I | DC Input Voltage | -0.5 to V _{CC} + 0.5 | V |
| V _O | DC Output Voltage | -0.5 to V _{CC} + 0.5 | V |
| I _{IK} | DC Input Diode Current | ± 20 | mA |
| I _{OK} | DC Output Diode Current | ± 20 | mA |
| I _O | DC Output Sink Current Per Output Pin | 25 | mA |
| I _{CC} or I _{GND} | DC V _{CC} or Ground Current | ± 50 | mA |
| P _D | Power Dissipation | 500 (*) | mW |
| T _{stg} | Storage Temperature | -65 to +150 | °C |
| T _L | Lead Temperature (10 sec) | 300 | °C |

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

(*) 500 mW: ± 65 °C derate to 300 mW by 10mW/°C: 65 °C to 85 °C

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | | Value | Unit |
|---------------------------------|---|-------------------------|---------------------------|----------|
| V _{CC} | Supply Voltage | | 2 to 6 | V |
| V _I | Input Voltage | | 0 to V _{CC} | V |
| V _O | Output Voltage | | 0 to V _{CC} | V |
| T _{op} | Operating Temperature: M54HC Series M74HC Series | | -55 to +125 -40 to +85 | °C °C |
| t _r , t _f | Input Rise and Fall Time | V _{CC} = 2 V | 0 to 1000 | ns |
| | | V _{CC} = 4.5 V | 0 to 500 | |
| | | V _{CC} = 6 V | 0 to 400 | |

DC SPECIFICATIONS

| Symbol | Parameter | Test Conditions | | Value | | | | | | Unit | | |
|-----------------|--------------------------|------------------------|--|---|-------------------------|------|----------------------|------|-----------------------|------|------|----|
| | | V _{CC} (V) | | T _A = 25 °C 54HC and 74HC | | | -40 to 85 °C 74HC | | -55 to 125 °C 54HC | | | |
| | | | | Min. | Typ. | Max. | Min. | Max. | Min. | | Max. | |
| V _{IH} | High Level Input Voltage | 2.0 | | 1.5 | | | 1.5 | | 1.5 | | V | |
| | | 4.5 | | 3.15 | | | 3.15 | | 3.15 | | | |
| | | 6.0 | | 4.2 | | | 4.2 | | 4.2 | | | |
| V _{IL} | Low Level Input Voltage | 2.0 | | | | 0.5 | | 0.5 | | 0.5 | V | |
| | | 4.5 | | | | 1.35 | | 1.35 | | 1.35 | | |
| | | 6.0 | | | | 1.8 | | 1.8 | | 1.8 | | |
| V _{OL} | Low Level Output Voltage | 2.0 | V _I = V _{IH} or V _{IL} | I _O = 20 μA | | 0.0 | 0.1 | | 0.1 | | 0.1 | V |
| | | 4.5 | | | | 0.0 | 0.1 | | 0.1 | | 0.1 | |
| | | 6.0 | | | | 0.0 | 0.1 | | 0.1 | | 0.1 | |
| | | 4.5 | | I _O = 4.0 mA | | 0.17 | 0.26 | | 0.33 | | 0.40 | |
| | | 6.0 | | | I _O = 5.2 mA | | 0.18 | 0.26 | | 0.33 | | |
| I _I | Input Leakage Current | 6.0 | V _I = V _{CC} or GND | | | | ±0.1 | | ±1 | | ±1 | μA |
| I _{OZ} | Output Leakage Current | 6.0 | V _I = V _{IH} or V _{IL} V _O = V _{CC} or GND | | | ±0.5 | | ±5 | | ±10 | μA | |
| I _{CC} | Quiescent Supply Current | 6.0 | V _I = V _{CC} or GND | | | 1 | | 10 | | 20 | μA | |

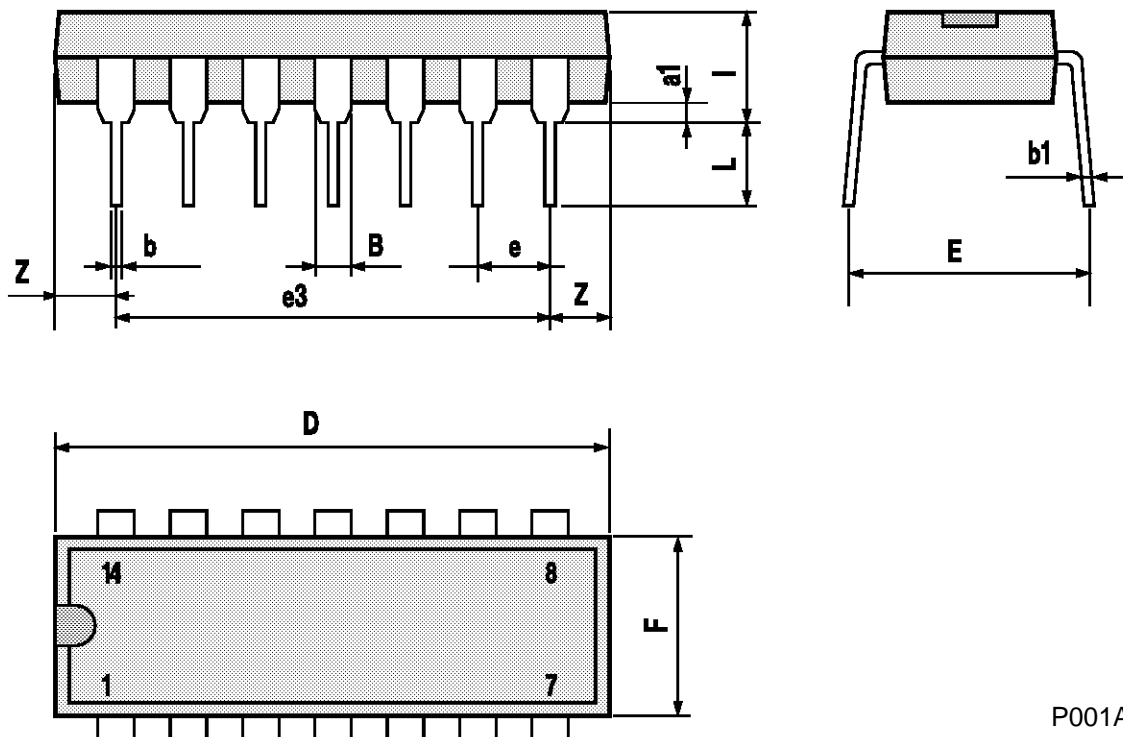
AC ELECTRICAL CHARACTERISTICS ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 6 \text{ ns}$)

| Symbol | Parameter | Test Conditions | | Value | | | | | | Unit | |
|---------------------|-------------------------------|------------------------|----------------------|---|------|------|----------------------|------|-----------------------|------|------|
| | | V _{CC} (V) | | T _A = 25 °C 54HC and 74HC | | | -40 to 85 °C 74HC | | -55 to 125 °C 54HC | | |
| | | | | Min. | Typ. | Max. | Min. | Max. | Min. | | Max. |
| t _{THL} | Output Transition Time | 2.0 | | | 30 | 75 | | 95 | | 110 | ns |
| | | 4.5 | | | 8 | 15 | | 19 | | 22 | |
| | | 6.0 | | | 7 | 13 | | 16 | | 19 | |
| t _{PLZ} | Propagation Delay Time | 2.0 | R _L = 1KΩ | | 20 | 90 | | 115 | | 135 | ns |
| | | 4.5 | | | 11 | 18 | | 23 | | 27 | |
| | | 6.0 | | | 10 | 15 | | 20 | | 23 | |
| t _{PZL} | Propagation Delay Time | 2.0 | R _L = 1KΩ | | 33 | 90 | | 115 | | 135 | ns |
| | | 4.5 | | | 9 | 18 | | 23 | | 27 | |
| | | 6.0 | | | 8 | 15 | | 20 | | 23 | |
| C _{IN} | Input Capacitance | | | | 5 | 10 | | 10 | | 10 | pF |
| C _{OUT} | Output Capacitance | | | | 10 | | | | | | pF |
| C _{PD} (*) | Power Dissipation Capacitance | | | | 6.5 | | | | | | pF |

(*) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load.

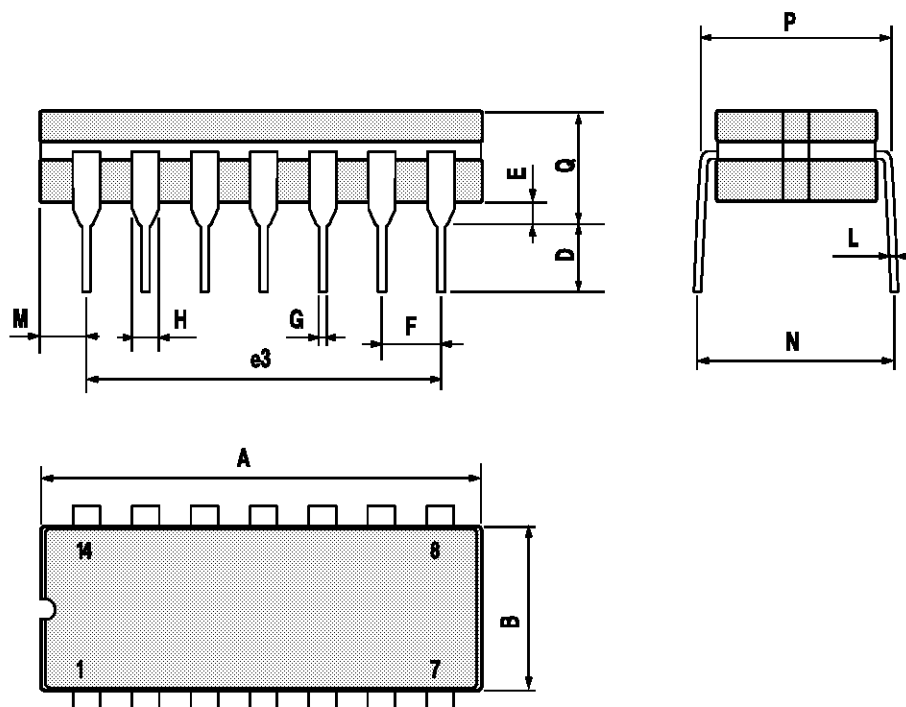
Plastic DIP14 MECHANICAL DATA

| DIM. | mm | | | inch | | |
|------|------|-------|------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| a1 | 0.51 | | | 0.020 | | |
| B | 1.39 | | 1.65 | 0.055 | | 0.065 |
| b | | 0.5 | | | 0.020 | |
| b1 | | 0.25 | | | 0.010 | |
| D | | | 20 | | | 0.787 |
| E | | 8.5 | | | 0.335 | |
| e | | 2.54 | | | 0.100 | |
| e3 | | 15.24 | | | 0.600 | |
| F | | | 7.1 | | | 0.280 |
| I | | | 5.1 | | | 0.201 |
| L | | 3.3 | | | 0.130 | |
| Z | 1.27 | | 2.54 | 0.050 | | 0.100 |



Ceramic DIP14/1 MECHANICAL DATA

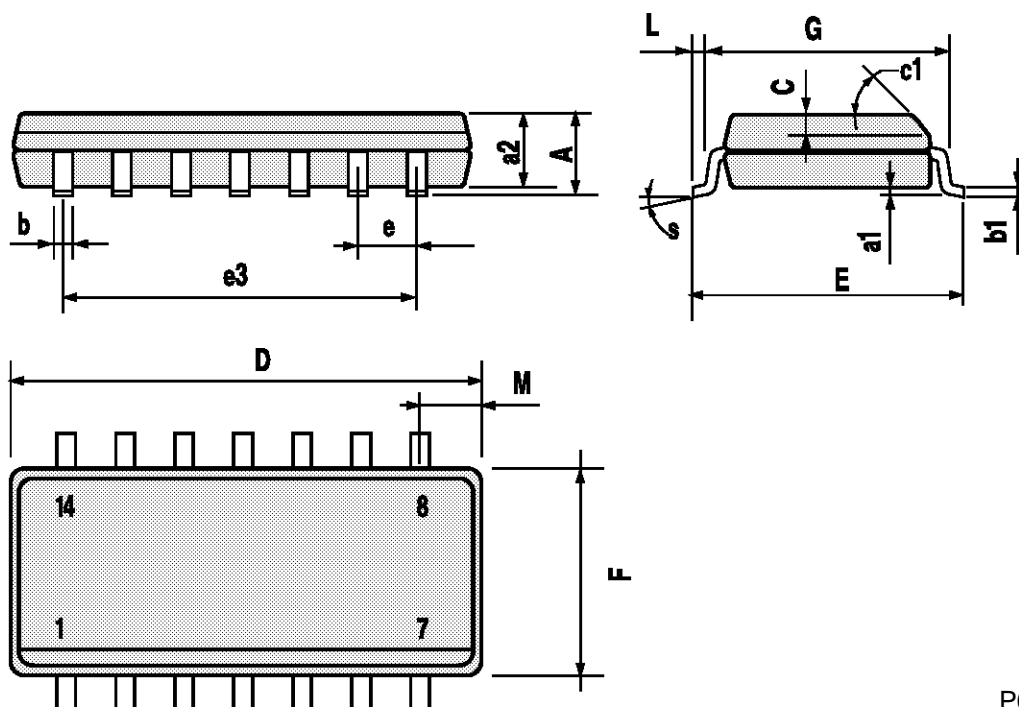
| DIM. | mm | | | inch | | |
|------|------|-------|------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | | | 20 | | | 0.787 |
| B | | | 7.0 | | | 0.276 |
| D | | 3.3 | | | 0.130 | |
| E | 0.38 | | | 0.015 | | |
| e3 | | 15.24 | | | 0.600 | |
| F | 2.29 | | 2.79 | 0.090 | | 0.110 |
| G | 0.4 | | 0.55 | 0.016 | | 0.022 |
| H | 1.17 | | 1.52 | 0.046 | | 0.060 |
| L | 0.22 | | 0.31 | 0.009 | | 0.012 |
| M | 1.52 | | 2.54 | 0.060 | | 0.100 |
| N | | | 10.3 | | | 0.406 |
| P | 7.8 | | 8.05 | 0.307 | | 0.317 |
| Q | | | 5.08 | | | 0.200 |



P053C

SO14 MECHANICAL DATA

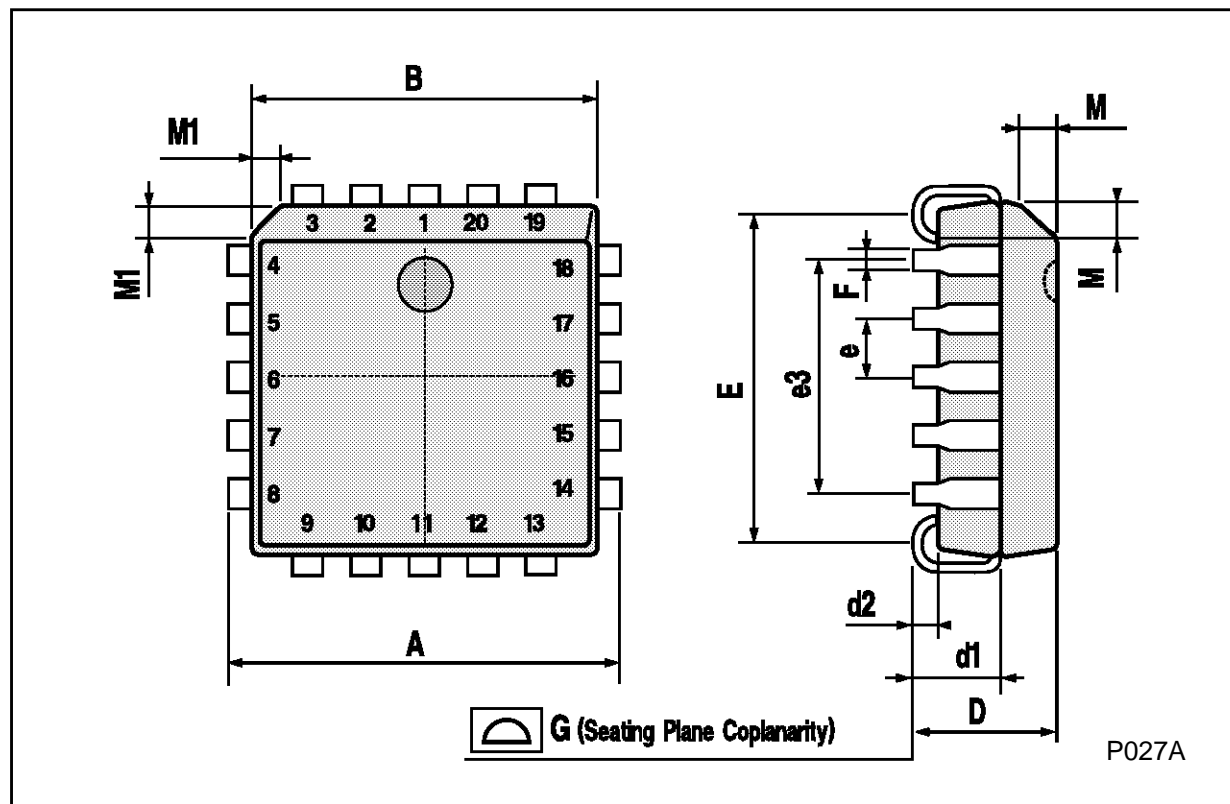
| DIM. | mm | | | inch | | |
|------|------------|------|------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | | | 1.75 | | | 0.068 |
| a1 | 0.1 | | 0.2 | 0.003 | | 0.007 |
| a2 | | | 1.65 | | | 0.064 |
| b | 0.35 | | 0.46 | 0.013 | | 0.018 |
| b1 | 0.19 | | 0.25 | 0.007 | | 0.010 |
| C | | 0.5 | | | 0.019 | |
| c1 | 45° (typ.) | | | | | |
| D | 8.55 | | 8.75 | 0.336 | | 0.344 |
| E | 5.8 | | 6.2 | 0.228 | | 0.244 |
| e | | 1.27 | | | 0.050 | |
| e3 | | 7.62 | | | 0.300 | |
| F | 3.8 | | 4.0 | 0.149 | | 0.157 |
| G | 4.6 | | 5.3 | 0.181 | | 0.208 |
| L | 0.5 | | 1.27 | 0.019 | | 0.050 |
| M | | | 0.68 | | | 0.026 |
| S | 8° (max.) | | | | | |



P013G

PLCC20 MECHANICAL DATA

| DIM. | mm | | | inch | | |
|------|------|------|-------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | 9.78 | | 10.03 | 0.385 | | 0.395 |
| B | 8.89 | | 9.04 | 0.350 | | 0.356 |
| D | 4.2 | | 4.57 | 0.165 | | 0.180 |
| d1 | | 2.54 | | | 0.100 | |
| d2 | | 0.56 | | | 0.022 | |
| E | 7.37 | | 8.38 | 0.290 | | 0.330 |
| e | | 1.27 | | | 0.050 | |
| e3 | | 5.08 | | | 0.200 | |
| F | | 0.38 | | | 0.015 | |
| G | | | 0.101 | | | 0.004 |
| M | | 1.27 | | | 0.050 | |
| M1 | | 1.14 | | | 0.045 | |



Information furnished is believed to be accurate and reliable. However, SGS-THOMSON Microelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of SGS-THOMSON Microelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. SGS-THOMSON Microelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of SGS-THOMSON Microelectronics.

© 1994 SGS-THOMSON Microelectronics - All Rights Reserved

SGS-THOMSON Microelectronics GROUP OF COMPANIES

Australia - Brazil - France - Germany - Hong Kong - Italy - Japan - Korea - Malaysia - Malta - Morocco - The Netherlands -
Singapore - Spain - Sweden - Switzerland - Taiwan - Thailand - United Kingdom - U.S.A